- **Flow-Through Architecture Optimizes PCB Layout**
- **Center-Pin V_{CC} and GND Configurations Minimize High-Speed Switching Noise**
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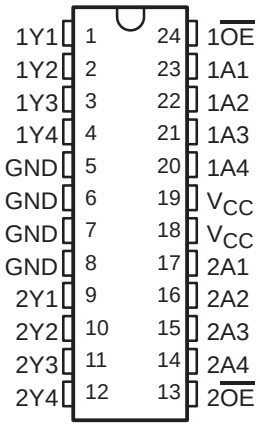
DB, DW, OR NT PACKAGE
(TOP VIEW)



description

This octal buffer/line driver is designed specifically to improve both the performance and density of 3-state memory address drivers, clock drivers, and bus-oriented receivers and transmitters. This device provides inverting outputs and symmetrical active-low output-enable ($\overline{OE}$) inputs. This device features high fan-out and improved fan-in.

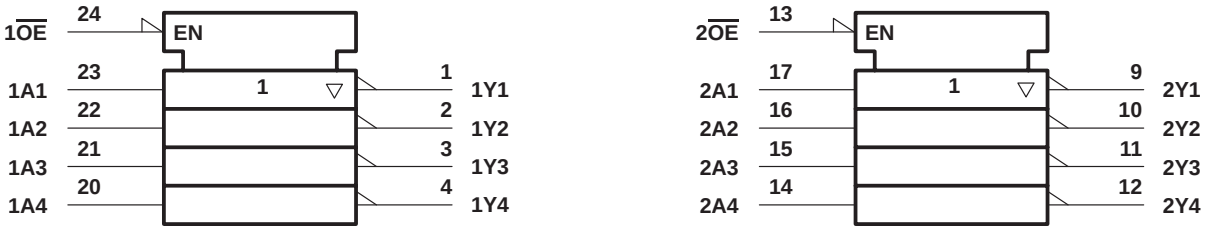
The 74AC11240 is organized as two 4-bit buffers/line drivers with separate $\overline{OE}$ inputs. When $\overline{OE}$ is low, the device passes inverted data from the A inputs to the Y outputs. When $\overline{OE}$ is high, the outputs are in the high-impedance state.

The 74AC11240 is characterized for operation from –40°C to 85°C.

FUNCTION TABLE
(each buffer)

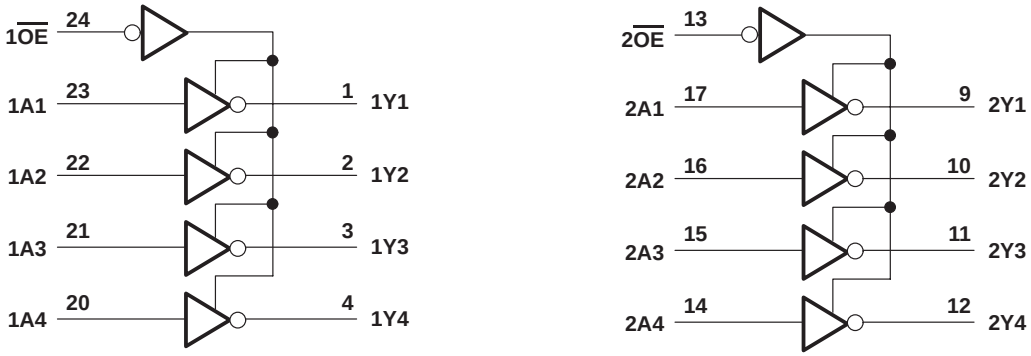
INPUTS		OUTPUT
$\overline{OE}$	A	Y
L	H	L
L	L	H
H	X	Z

logic symbol†



† This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

logic diagram (positive logic)



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V_{CC} . . . . . –0.5 V to 6 V
Input voltage range, V_I (see Note 1) . . . . . –0.5 V to V_{CC} + 0.5 V
Output voltage range, V_O (see Note 1) . . . . . –0.5 V to V_{CC} + 0.5 V
Input clamp current, I_{IK} (V_I < 0 or V_I > V_{CC}) . . . . . ±20 mA
Output clamp current, I_{OK} (V_O < 0 or V_O > V_{CC}) . . . . . ±50 mA
Continuous output current, I_O (V_O = 0 to V_{CC}) . . . . . ±50 mA
Continuous current through V_{CC} or GND . . . . . ±200 mA
Maximum power dissipation at T_A = 55°C (in still air) (see Note 2): DB package . . . . . 0.65 W
DW package . . . . . 1.7 W
NT package . . . . . 1.3 W
Storage temperature range, T_{stg} . . . . . –65°C to 150°C

† Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.
2. The maximum package power dissipation is calculated using a junction temperature of 150°C and a board trace length of 750 mils, except for the NT package, which has a trace length of zero.

recommended operating conditions

			MIN	NOM	MAX	UNIT
V_{CC}	Supply voltage		3	5	5.5	V
V_{IH}	High-level input voltage	V_{CC} = 3 V	2.1			V
		V_{CC} = 4.5 V	3.15			
		V_{CC} = 5.5 V	3.85			
V_{IL}	Low-level input voltage	V_{CC} = 3 V			0.9	V
		V_{CC} = 4.5 V			1.35	
		V_{CC} = 5.5 V			1.65	
V_I	Input voltage		0		V_{CC}	V
V_O	Output voltage		0		V_{CC}	V
I_{OH}	High-level output current	V_{CC} = 3 V			–4	mA
		V_{CC} = 4.5 V			–24	
		V_{CC} = 5.5 V			–24	
I_{OL}	Low-level output current	V_{CC} = 3 V			12	mA
		V_{CC} = 4.5 V			24	
		V_{CC} = 5.5 V			24	
$\Delta t/\Delta v$	Input transition rise or fall rate	$\overline{OE}$	0		5	ns/V
		Data	0		10	
T_A	Operating free-air temperature		–40		85	°C

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V_{CC}	T_A = 25°C			MIN	MAX	UNIT
			MIN	TYP	MAX			
V_{OH}	I_{OH} = –50 μA	3 V	2.9			2.9		V
		4.5 V	4.4			4.4		
		5.5 V	5.4			5.4		
	I_{OH} = –4 mA	3 V	2.58			2.48		
	I_{OH} = –24 mA	4.5 V	3.94			3.8		
		5.5 V	4.94			4.8		
	I_{OH} = –75 mA†	5.5 V				3.85		
V_{OL}	I_{OL} = 50 μA	3 V			0.1		0.1	V
		4.5 V			0.1		0.1	
		5.5 V			0.1		0.1	
	I_{OL} = 12 mA	3 V			0.36		0.44	
	I_{OL} = 24 mA	4.5 V			0.36		0.44	
		5.5 V			0.36		0.44	
	I_{OL} = 75 mA†	5.5 V					1.65	
I_{OZ}	V_O = V_{CC} or GND	5.5 V			±0.5		±5	μA
I_I	V_I = V_{CC} or GND	5.5 V			±0.1		±1	μA
I_{CC}	V_I = V_{CC} or GND, I_O = 0	5.5 V			8		80	μA
C_i	V_I = V_{CC} or GND	5 V		4				pF
C_O	V_O = V_{CC} or GND	5 V		10				pF

† Not more than one output should be tested at a time, and the duration of the test should not exceed 10 ms.

switching characteristics over recommended operating free-air temperature range, V_{CC} = 3.3 V ± 0.3 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	T_A = 25°C			MIN	MAX	UNIT
			MIN	TYP	MAX			
t_{PLH}	A	Y	1.5	7.6	10.5	1.5	11.7	ns
t_{PHL}			1.5	6.3	8.6	1.5	9.5	
t_{PZH}	$\overline{OE}$	Y	1.5	8.2	11.6	1.5	12.7	ns
t_{PZL}			1.5	7.6	10.8	1.5	12	
t_{PHZ}	$\overline{OE}$	Y	1.5	5.5	7.5	1.5	7.8	ns
t_{PLZ}			1.5	6.7	9.4	1.5	9.8	

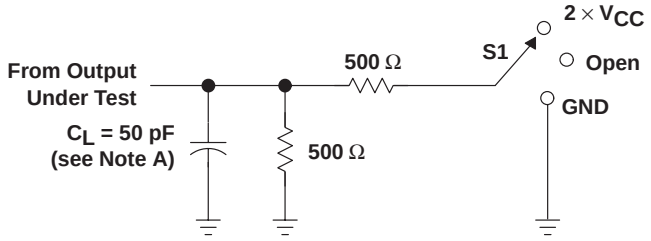
switching characteristics over recommended operating free-air temperature range, V_{CC} = 5 V ± 0.5 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	T_A = 25°C			MIN	MAX	UNIT
			MIN	TYP	MAX			
t_{PLH}	A	Y	1.5	5.4	7.5	1.5	8.4	ns
t_{PHL}			1.5	4.6	6.6	1.5	7.2	
t_{PZH}	$\overline{OE}$	Y	1.5	5.7	8.2	1.5	9.2	ns
t_{PZL}			1.5	5.3	7.7	1.5	8.7	
t_{PHZ}	$\overline{OE}$	Y	1.5	4.7	6.3	1.5	6.6	ns
t_{PLZ}			1.5	5.2	7.3	1.5	7.7	

operating characteristics, V_{CC} = 5 V, T_A = 25°C

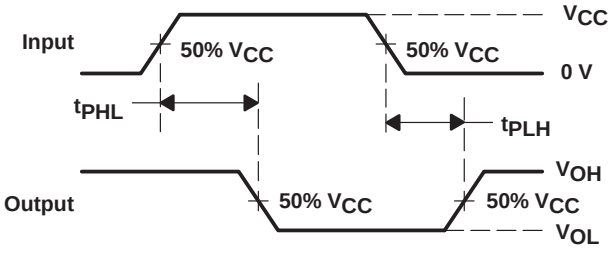
PARAMETER			TEST CONDITIONS		TYP	UNIT
C_{pd}	Power dissipation capacitance per buffer	Outputs enabled	C_L = 50 pF,	f = 1 MHz	39	pF
		Outputs disabled			12	

PARAMETER MEASUREMENT INFORMATION

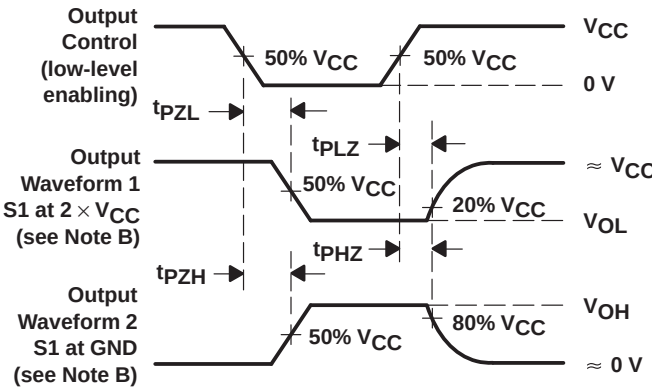


TEST	S1
t_{PLH}/t_{PHL}	Open
t_{PLZ}/t_{PZL}	2 × V_{CC}
t_{PHZ}/t_{PZH}	GND

LOAD CIRCUIT



VOLTAGE WAVEFORMS



VOLTAGE WAVEFORMS

NOTES: A. C_L includes probe and jig capacitance.
B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
C. All input pulses are supplied by generators having the following characteristics: PRR ≤ 1 MHz, Z_O = 50 Ω, t_r = 3 ns, t_f = 3 ns.
D. The outputs are measured one at a time with one input transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms

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PRODUCT FOLDER | PRODUCT INFO: FEATURES | DESCRIPTION | DATASHEETS | PRICING/AVAILABILITY/PKG | APPLICATION NOTES | USER GUIDES | MORE LITERATURE

PRODUCT SUPPORT: TRAINING

74AC11240, Octal Buffers / Drivers

DEVICE STATUS: **ACTIVE**

PARAMETER NAME	74AC11240
Voltage Nodes (V)	5, 3.3
Vcc range (V)	3.0 to 5.5
Input Level	CMOS
Output Level	CMOS
No. of Outputs	8
Output Drive (mA)	-24/24
tpd max (ns)	8.4
Static Current	0.08
Logic	Inv

FEATURES

Back to Top

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Back to Top

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TECHNICAL DOCUMENTS

Back to Top

To view the following documents, Acrobat Reader 4.0 is required.
To download a document to your hard drive, right-click on the link and choose 'Save'.

DATASHEET

Back to Top

Full datasheet in Acrobat PDF: 74ac11240.pdf (96 KB,Rev.A) (Updated: 04/01/1996)

APPLICATION NOTES

Back to Top

View Application Notes for Digital Logic

- CMOS Power Consumption and CPD Calculation (Rev. B) (SCAA035B - Updated: 06/01/1997)
- Designing With Logic (Rev. C) (SDYA009C - Updated: 06/01/1997)
- Evaluation of Nickel/Palladium/Gold-Finished Surface-Mount Integrated Circuits (SZZA026 - Updated: 06/20/2001)
- Implications of Slow or Floating CMOS Inputs (Rev. C) (SCBA004C - Updated: 02/01/1998)
- Input and Output Characteristics of Digital Integrated Circuits (SDYA010 - Updated: 10/01/1996)
- Live Insertion (SDYA012 - Updated: 10/01/1996)
- TI IBIS File Creation, Validation, and Distribution Processes (SZZA034 - Updated: 08/29/2002)
- Understanding and Interpreting Texas Instruments Standard-Logic Products Data Sh (Rev. A) (SZZA036A - Updated: 02/27/2003)
- Using High Speed CMOS and Advanced CMOS in Systems With Multiple Vcc (SCLA008 - Updated: 04/01/1996)

MORE LITERATURE

Back to Top

- Enhanced Plastic Portfolio Brochure (SGZB004, 387 KB - Updated: 08/19/2002)
- Logic Reference Guide (SCYB004, 1032 KB - Updated: 10/23/2001)
- MicroStar Junior BGA Design Summary (SCET004, 167 KB - Updated: 07/28/2000)
- Military Brief (SGYN138, 803 KB - Updated: 10/10/2000)
- Overview of IEEE Std 91-1984, Explanation of Logic Symbols Training Booklet (Rev. A) (SDYZ001A, 138 KB - Updated: 07/01/1996)
- Palladium Lead Finish User's Manual (SDYV001, 2041 KB - Updated: 11/01/1996)
- QML Class V Space Products Military Brief (Rev. A) (SGZN001A, 257 KB - Updated: 10/07/2002)

USER GUIDES

Back to Top

- LOGIC Pocket Data Book (SCYD013, 4837 KB - Updated: 12/05/2002)

PRICING/AVAILABILITY/PKG

Back to Top

DEVICE INFORMATION
Updated Daily

ORDERABLE DEVICE	STATUS	PACKAGE TYPE | PINS	TEMP (°C)	PRODUCT CONTENT	BUDGETARY PRICING QTY | $US	STD PACK QTY
74AC11240DBLE	OBSOLETE	SSOP (DB) | 24	-40 TO 85	View Contents	1KU |	
74AC11240DBR	ACTIVE	SSOP (DB) | 24	-40 TO 85	View Contents	1KU | 1.50	2000
74AC11240DW	ACTIVE	SOIC (DW) | 24	-40 TO 85	View Contents	1KU | 1.50	25
74AC11240DWR	ACTIVE	SOIC (DW) | 24	-40 TO 85	View Contents	1KU | 1.54	2000
74AC11240NT	ACTIVE	PDIP (NT) | 24	-40 TO 85	View Contents	1KU | 1.50	15
74AC11240PW	ACTIVE	TSSOP (PW) | 24	-40 TO 85	View Contents	1KU | 0.95	60

TI INVENTORY STATUS
As Of 08:00 AM GMT, 17 Apr 2003

IN STOCK	IN PROGRESS QTY | DATE	LEAD TIME
0*		Call**
4000*	>10k | 12 May	7 WKS
0*	390 | 28 Apr	8 WKS
	>10k | 12 May	
0*	>10k | 12 May	8 WKS
2640*	>10k | 02 May	7 WKS
0*	720 | 16 Apr	7 WKS

REPORTED DISTRIBUTOR INVENTORY
As Of 08:00 AM GMT, 17 Apr 2003

DISTRIBUTOR COMPANY | REGION	IN STOCK	PURCHASE
None Reported View Distributors		
DigiKey | Americas	>1k	BUY NOW
None Reported View Distributors		
None Reported View Distributors		
Arrow | Americas	165	BUY NOW
Avnet | Americas	>1k	BUY NOW

								>10k | 28 Apr				
74AC11240PWR	ACTIVE	TSSOP (PW) | 24	-40 TO 85	View Contents	1KU | 1.50	2000	0*	>10k | 05 May	7 WKS	Avnet | Americas	>1k	BUY NOW

Table Data Updated on: 4/17/2003
